NSN 5962-01-254-6232

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View Online at https://aerobasegroup.com/nsn/5962-01-254-6232

Body Length:

Between 0.970 inches and 1.010 inches

Body Width:

Between 0.280 inches and 0.300 inches

Body Height:

0.155 inches

Maximum Power Dissipation Rating:

1.02 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Programmable and schottky and monolithic and bipolar and 3-state output and high impedance

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Precious Material And Location:

Terminal surfaces option gold

Precious Material:

Gold

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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